

# X-Class HiPerFET™ **Power MOSFET**

# IXFT50N85XHV IXFH50N85X IXFK50N85X

N-Channel Enhancement Mode Avalanche Rated Fast Intrinsic Diode



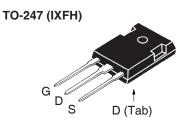
Symbol Test Conditions		Maximum Ratings	
V <sub>DSS</sub>	$T_J = 25^{\circ}C \text{ to } 150^{\circ}C$	850	V
V <sub>DGR</sub>	$T_{_{ m J}}$ = 25°C to 150°C, $R_{_{ m GS}}$ = 1M $\Omega$	850	V
V <sub>GSS</sub>	Continuous	±30	V
V <sub>GSM</sub>	Transient	±40	V
I <sub>D25</sub>	T <sub>C</sub> = 25°C	50	A
I <sub>DM</sub>	$T_{\rm C}^{\rm T}$ = 25°C, Pulse Width Limited by $T_{\rm JM}$	125	Α
I <sub>A</sub>	T <sub>C</sub> = 25°C	25	Α
E <sub>AS</sub>	$T_{c} = 25^{\circ}C$	2	J
dv/dt	$I_{_{\mathrm{S}}} \leq I_{_{\mathrm{DM}}}, V_{_{\mathrm{DD}}} \leq V_{_{\mathrm{DSS}}}, T_{_{\mathrm{J}}} \leq 150^{\circ}\mathrm{C}$	50	V/ns
$\overline{P_{D}}$	T <sub>c</sub> = 25°C	890	W
T <sub>J</sub>		-55 +150	°C
$T_{JM}$		150	°C
T <sub>stg</sub>		-55 +150	°C
T,	Maximum Lead Temperature for Soldering	300	°C
T <sub>SOLD</sub>	1.6 mm (0.062in.) from Case for 10s	260	°C
$M_d$	Mounting Torque (TO-247 & TO-264)	1.13 / 10	Nm/lb.in
Weight	TO-268HV	4	g
	TO-247 TO-264	6 10	g g

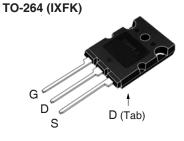
SymbolTest ConditionsCharacteristics $(T_J = 25^{\circ}C, Unless Otherwise Specified)$ Min.		cteristic Values Typ.   Max.			
BV <sub>DSS</sub>	$V_{GS} = 0V, I_D = 1mA$	850			V
$V_{\rm GS(th)}$	$V_{DS} = V_{GS}$ , $I_{D} = 4mA$	3.5		5.5	V
l <sub>GSS</sub>	$V_{gs} = \pm 30V, V_{DS} = 0V$			±100	nA
I <sub>DSS</sub>	$V_{DS} = V_{DSS}$ , $V_{GS} = 0V$ $T_{J} = 125^{\circ}C$				μA mA
R <sub>DS(on)</sub>	$V_{GS} = 10V, I_{D} = 0.5 \cdot I_{D25}, Note 1$			105	mΩ

850V 50A D25  $105m\Omega$  $\leq$ R<sub>DS(on)</sub>

# TO-268HV (IXFT)







G = Gate	D	=	Drain
S = Source	Tab	=	Drain

#### **Features**

- International Standard Packages
- High Voltage Package
- Low R<sub>DS(ON)</sub> and Q<sub>G</sub>
   Avalanche Rated
- Low Package Inductance

#### **Advantages**

- High Power Density
- Easy to Mount
- Space Savings

## **Applications**

- Switch-Mode and Resonant-Mode **Power Supplies**
- DC-DC Converters
- PFC Circuits
- AC and DC Motor Drives
- Robotics and Servo Controls



Symbol	Symbol Test Conditions Cha		racteristic Values	
$(T_J = 25^{\circ}C, Unless Otherwise Specified)$ Min.		Typ.	Max	
g <sub>fs</sub>	$V_{DS} = 10V, I_{D} = 0.5 \cdot I_{D25}, Note 1$ 19	32	S	
R <sub>Gi</sub>	Gate Input Resistance	0.6	Ω	
C <sub>iss</sub>	)	4480	pF	
C <sub>oss</sub>	$V_{GS} = 0V, V_{DS} = 25V, f = 1MHz$	4863	pF	
C <sub>rss</sub>	J	116	pF	
	Effective Output Capacitance			
$\mathbf{C}_{o(er)}$	Energy related $\bigvee_{GS} = 0V$	180	pF	
$\mathbf{C}_{o(tr)}$	Time related $\int_{DS}^{GS} V_{DS} = 0.8 \cdot V_{DSS}$	750	pF	
t <sub>d(on)</sub>	Resistive Switching Times	27	ns	
t <sub>r</sub>	$V_{GS} = 10V, V_{DS} = 0.5 \cdot V_{DSS}, I_{D} = 0.5 \cdot I_{D25}$	30	ns	
$\mathbf{t}_{d(off)}$	$R_{G} = 10$ (External)	69	ns	
t <sub>f</sub>	) III <sub>G</sub> = 152 (External)	14	ns	
$\mathbf{Q}_{g(on)}$	)	152	nC	
$\mathbf{Q}_{gs}$	$V_{GS} = 10V, V_{DS} = 0.5 \cdot V_{DSS}, I_{D} = 0.5 \cdot I_{D25}$	28	nC	
$\mathbf{Q}_{gd}$	J	88	nC	
R <sub>thJC</sub>			0.14 °C/W	
$\mathbf{R}_{thCS}$	TO-247	0.21	°C/W	
	TO-264P	0.15	°C/W	

## Source-Drain Diode

SymbolTest ConditionsChara $(T_J = 25^{\circ}C, Unless Otherwise Specified)$ Min.		cteristic Typ.	Values Max		
I <sub>s</sub>	$V_{GS} = 0V$			50	Α
I <sub>SM</sub>	Repetitive, pulse Width Limited by ${\rm T}_{_{\rm JM}}$			200	Α
V <sub>SD</sub>	$I_F = I_S$ , $V_{GS} = 0V$ , Note 1			1.4	V
$\left. egin{array}{c} \mathbf{t}_{rr} & \\ \mathbf{Q}_{RM} & \\ \mathbf{I}_{RM} & \end{array}  ight.  ight.$	$I_F = 25A$ , -di/dt = 100A/ $\mu$ s $V_R = 100V$		218 1.85 17.0		ns µC A

Note 1. Pulse test,  $t \le 300 \mu s$ , duty cycle,  $d \le 2\%$ .

Fig. 1. Output Characteristics @  $T_J = 25^{\circ}C$ 

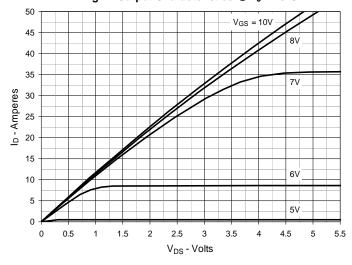


Fig. 2. Extended Output Characteristics @ T<sub>J</sub> = 25°C

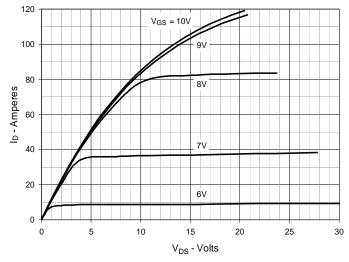


Fig. 3. Output Characteristics @ T<sub>J</sub> = 125°C

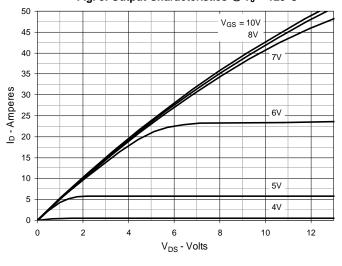


Fig. 4.  $R_{DS(on)}$  Normalized to  $I_D$  = 25A Value vs.

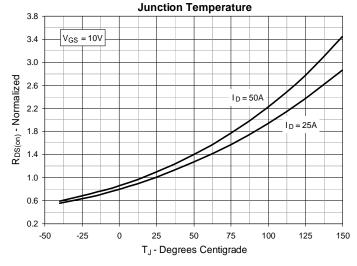


Fig. 5.  $R_{DS(on)}$  Normalized to  $I_D$  = 25A Value vs.

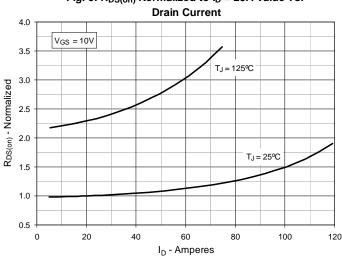
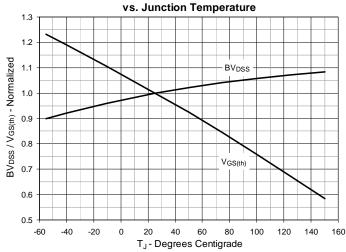
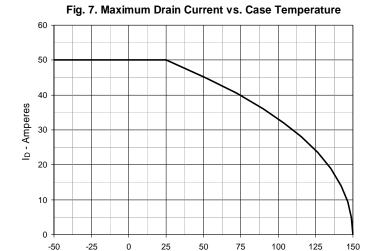


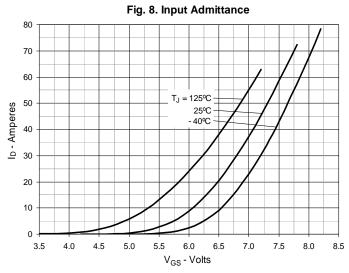
Fig. 6. Normalized Breakdown & Threshold Voltages vs. Junction Temperature

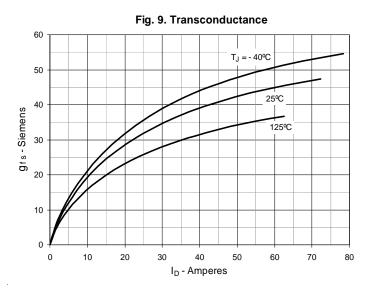


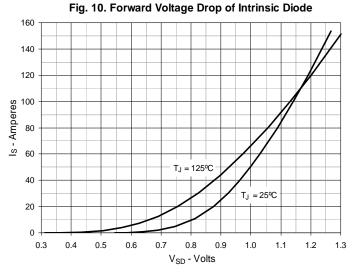


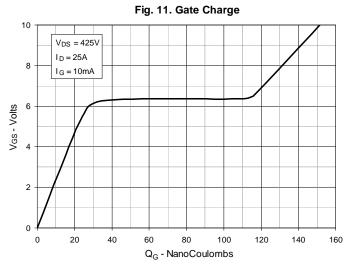


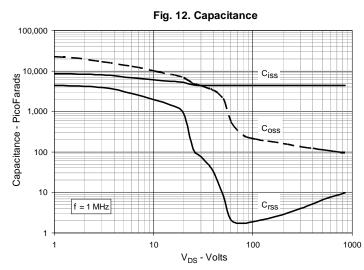
T<sub>C</sub> - Degrees Centigrade





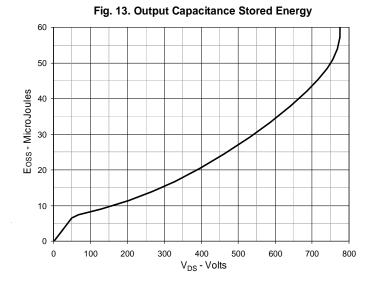






IXYS Reserves the Right to Change Limits, Test Conditions, and Dimensions.





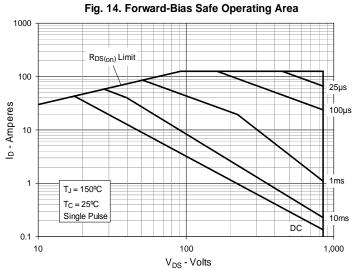
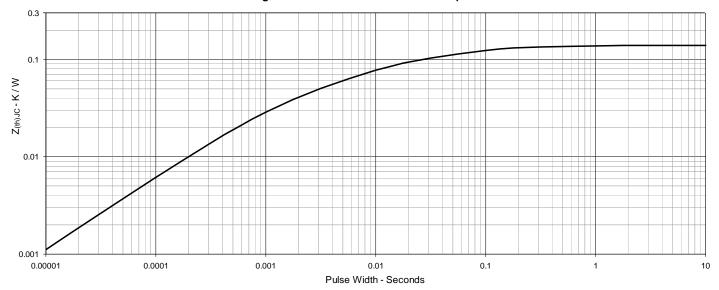
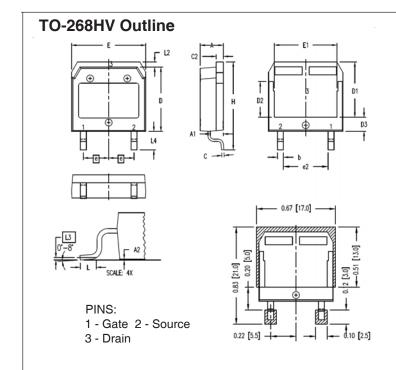


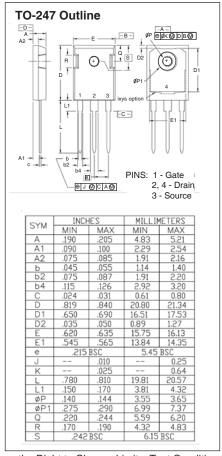
Fig. 15. Maximum Transient Thermal Impedance

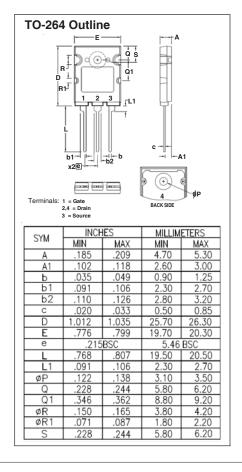






C)/1/4	INCHES		MILLIMETER	
SYM	MIN	MAX	MIN	MAX
Α	.193	.201	4.90	5.10
Α1	.106	.114	2.70	2.90
A2	.001	.010	0.02	0.25
Ь	.045	.057	1.15	1.45
С	.016	.026	0.40	0.65
C2	.057	.063	1.45	1.60
D	.543	.551	13.80	14.00
D1	.465	.476	11.80	12.10
D2	.295	.307	7.50	7.80
D3	.114	.126	2.90	3.20
E	.624	.632	15.85	16.05
E1	.524	.535	13.30	13.60
е		BSC	5.45 BSC	
(e2)	.374	.386	9.50	9.80
Η	.736	.752	18.70	19.10
L	.067	.079	1.70	2.00
L2	.039	.0 <b>4</b> 5	1.00	1.15
L3	.010	BSC	0.25 BSC	
L4	.150	.161	3.80	<b>4</b> .10





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